Diode Semiconductor Device - Page 1 of 1



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	re Material:
Metal	
Overall	Length:
0.450 in	ches
Overall	Diameter:
Between	n 0.667 inches and 0.687 inches
Mountin	ng Facility Quantity:
1	
Joint El	lectronic Device Engineering Council/jedec/case Outline Designation:
Do-5	
Mountir	ng Method:
Threade	ed stud
Feature	es Provided:
Hermeti	cally sealed case
Thread	Size:
0.250 in	ches
Semico	nductor Material:
Silicon	
Voltage	Rating In Volts Per Characteristic:
400.0 r	everse voltage, peak
Current	Rating Per Characteristic:
25.00 aı	mperes forward current, average absolute
Maximu	Im Operating Tempurature Per Measurement Point:
200.0 de	egrees celsius junction
Thread	Series Designator:
Unf	
Termina	al Type And Quantity:
1 tab, s	older lug and 1 threaded stud
Shelf Li	ife:
N/a	
Unit Of	Measure:
Demilita	arization:
No	
Fiig:	
A110a0	